

# 2MBI600VJ-120-50

**IGBT Modules**

## IGBT MODULE (V series) 1200V / 600A / 2 in one package

### ■ Features

- High speed switching
- Voltage drive
- Low Inductance module structure

### ■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as Welding machines



### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions	Maximum ratings	Units	
Inverter	Collector-Emitter voltage	V <sub>CEs</sub>	1200	V	
	Gate-Emitter voltage	V <sub>GES</sub>	±20	V	
	Collector current	I <sub>c</sub>	Continuous	T <sub>c</sub> =25°C T <sub>c</sub> =100°C	750 600
		I <sub>c</sub> pulse	1ms		1200
		-I <sub>c</sub>			600
		-I <sub>c</sub> pulse	1ms		1200
Collector power dissipation	P <sub>c</sub>	1 device		3750	
Junction temperature	T <sub>j</sub>			175	
Operating junction temperature (under switching conditions)	T <sub>jop</sub>			150	
Case temperature	T <sub>c</sub>			125	
Storage temperature	T <sub>stg</sub>			-40 to +125	
Isolation voltage	V <sub>iso</sub>	AC : 1min.		2500	
Screw torque	between terminal and copper base (*1) between thermistor and others (*2)			3.5	
	Mounting (*3)			4.5	
	Terminals (*4)			0.6	
	PC-Board (*5)				

Note \*1: All terminals should be connected together during the test.

Note \*2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note \*3: Recommendable value : 2.5-3.5 Nm (M5) Note \*4: Recommendable value : 3.5-4.5 Nm (M6)

Note \*5: Recommendable value : 0.4-0.6 Nm (M2.5)

#### ● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero gate voltage collector current	I <sub>CEs</sub>	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V	-	-	3.0	mA	
Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>CE</sub> = 0V, V <sub>GE</sub> = ±20V	-	-	600	nA	
Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	V <sub>CE</sub> = 20V, I <sub>c</sub> = 600mA	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>c</sub> = 600A	T <sub>j</sub> =25°C	-	2.45	2.90	V
			T <sub>j</sub> =125°C	-	2.80	-	
			T <sub>j</sub> =150°C	-	2.85	-	
	V <sub>CE(sat)</sub> (chip)		T <sub>j</sub> =25°C	-	1.85	2.30	
			T <sub>j</sub> =125°C	-	2.20	-	
			T <sub>j</sub> =150°C	-	2.25	-	
Internal gate resistance	R <sub>g(int)</sub>	-	-	1.25	-	Ω	
Input capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz	-	48	-	nF	
Turn-on time	t <sub>on</sub>	V <sub>CC</sub> = 600V	-	550	-	nsec	
	t <sub>r</sub>	I <sub>c</sub> = 600A	-	180	-		
	t <sub>r(i)</sub>	V <sub>GE</sub> = ±15V	-	120	-		
	t <sub>off</sub>	R <sub>g</sub> = 0.62Ω	-	1050	-		
Turn-off time	t <sub>f</sub>	L <sub>s</sub> = 80nH	-	110	-	nsec	
			-				
Forward on voltage	V <sub>F</sub> (terminal)	V <sub>GE</sub> = 0V I <sub>F</sub> = 600A	T <sub>j</sub> =25°C	-	2.30	2.75	V
			T <sub>j</sub> =125°C	-	2.45	-	
			T <sub>j</sub> =150°C	-	2.40	-	
	V <sub>F</sub> (chip)		T <sub>j</sub> =25°C	-	1.70	2.15	
			T <sub>j</sub> =125°C	-	1.85	-	
			T <sub>j</sub> =150°C	-	1.80	-	
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 600A	-	200	-	nsec	
Resistance	R	T=25°C	-	5000	-	Ω	
		T=100°C	465	495	520		
B value	B	T=25/50°C	3305	3375	3450	K	

● Thermal resistance characteristics

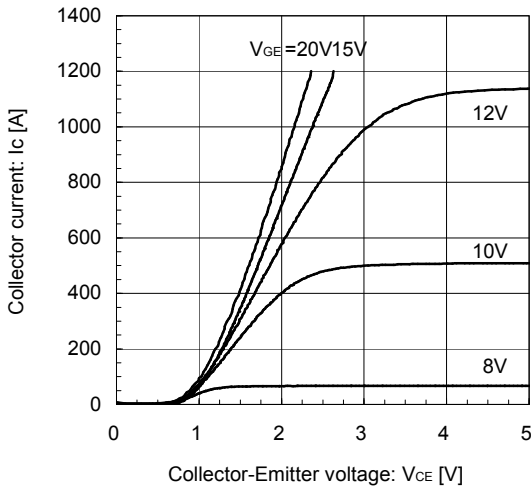
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	Rth(j-c)	Inverter IGBT	-	-	0.04	°C/W
		Inverter FWD	-	-	0.06	
Contact thermal resistance (1device) (*6)	Rth(c-f)	with Thermal Compound	-	0.0167	-	

Note \*6: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

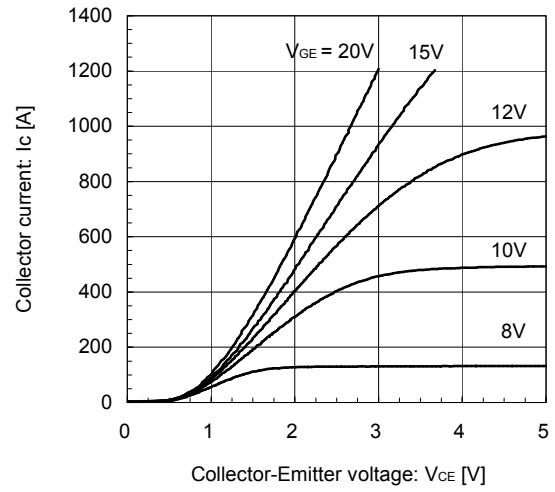
[INVERTER]

Collector current vs. Collector-Emmitter voltage (typ.)  
Tj= 25°C / chip



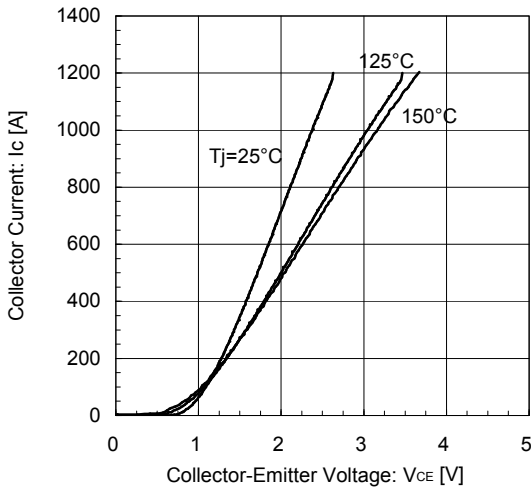
[INVERTER]

Collector current vs. Collector-Emmitter voltage (typ.)  
Tj= 150°C / chip



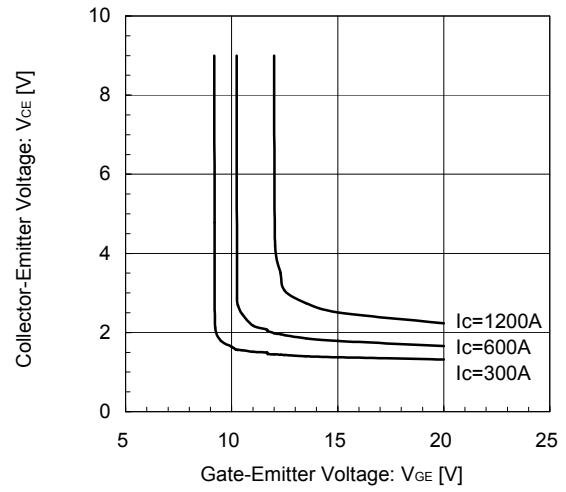
[INVERTER]

Collector current vs. Collector-Emmitter voltage (typ.)  
VGE= 15V / chip



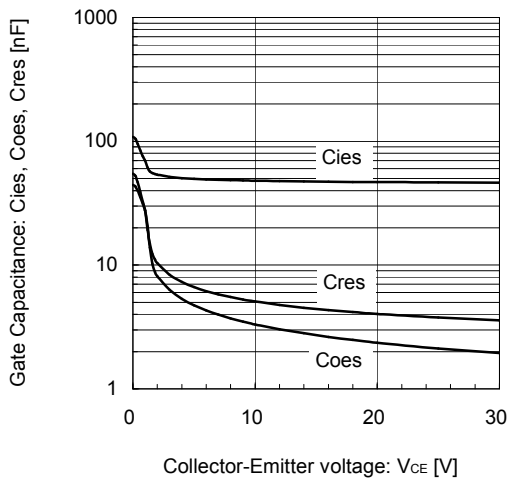
[INVERTER]

Collector-Emmitter voltage vs. Gate-Emmitter voltage (typ.)  
Tj= 25°C / chip



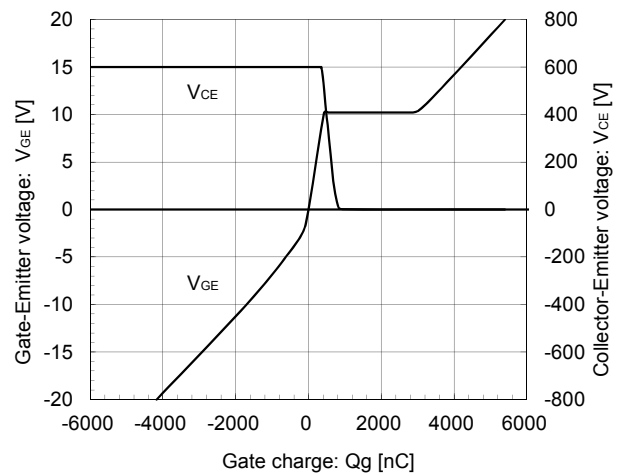
[INVERTER]

Gate Capacitance vs. Collector-Emmitter Voltage (typ.)  
VGE= 0V, f= 1MHz, Tj= 25°C



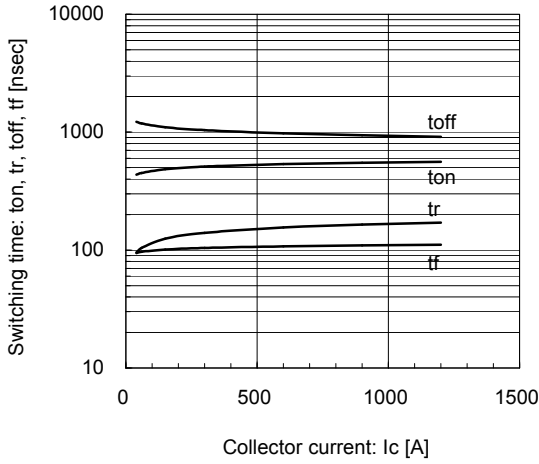
[INVERTER]

Dynamic Gate Charge (typ.)  
Vcc=600V, Ic=600A, Tj= 25°C



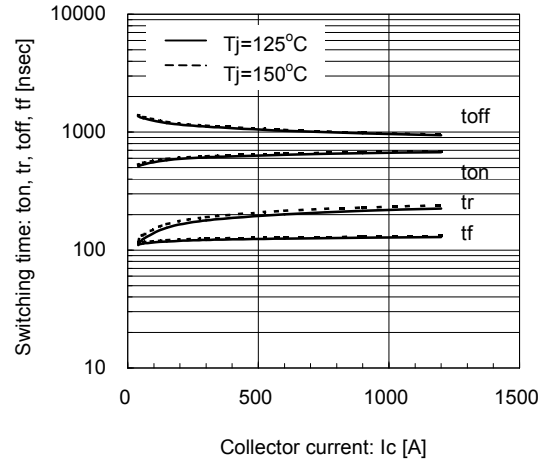
[INVERTER]

Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_g=0.62\Omega, T_j=25^\circ C$



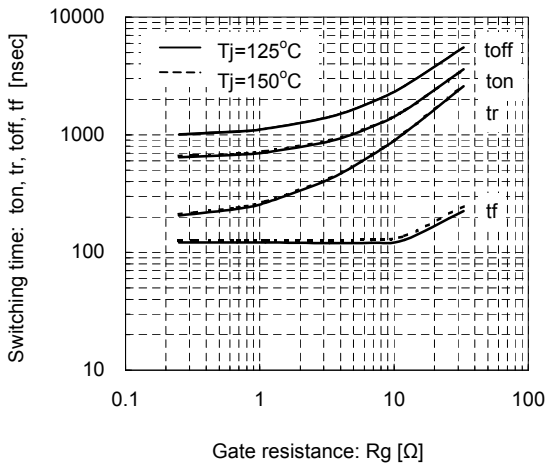
[INVERTER]

Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_g=0.62\Omega, T_j=125^\circ C, 150^\circ C$



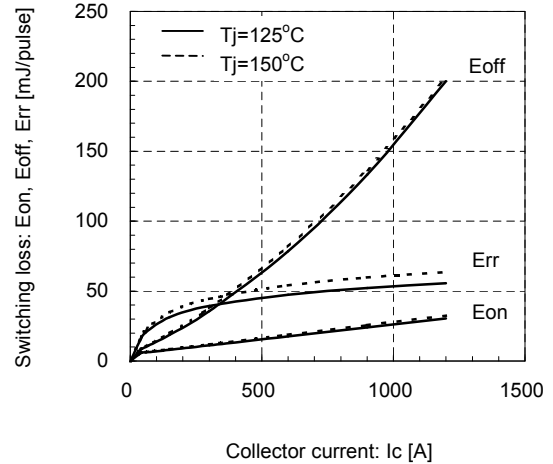
[INVERTER]

Switching time vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_c=600A, V_{GE}=\pm 15V, T_j=125^\circ C, 150^\circ C$



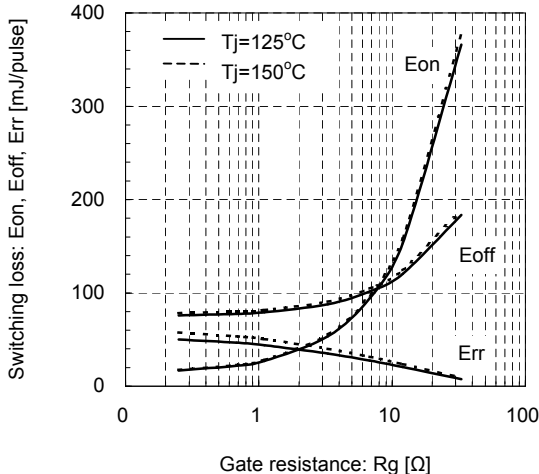
[INVERTER]

Switching loss vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_g=0.62\Omega, T_j=125^\circ C, 150^\circ C$



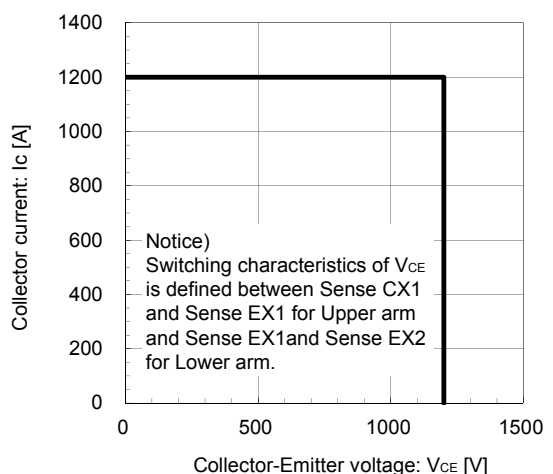
[INVERTER]

Switching loss vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_c=600A, V_{GE}=\pm 15V, T_j=125^\circ C, 150^\circ C$



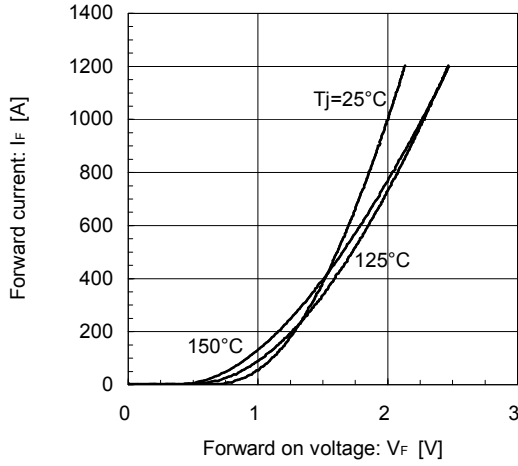
[INVERTER]

Reverse bias safe operating area (max.)  
 $+V_{GE}=15V, -V_{GE}=15V, R_g=0.62\Omega, T_j=150^\circ C$



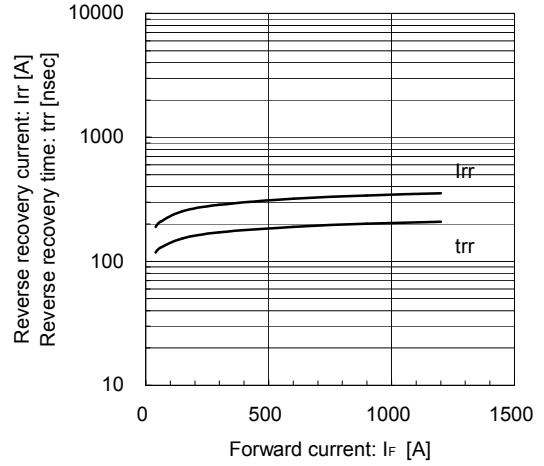
[INVERTER]

Forward Current vs. Forward Voltage (typ.)  
chip



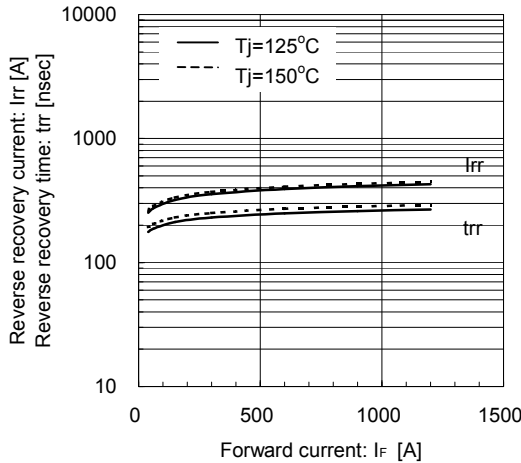
[INVERTER]

Reverse Recovery Characteristics (typ.)  
V<sub>CC</sub>=600V, V<sub>GE</sub>=±15V, R<sub>G</sub>=0.62Ω, T<sub>J</sub>=25°C

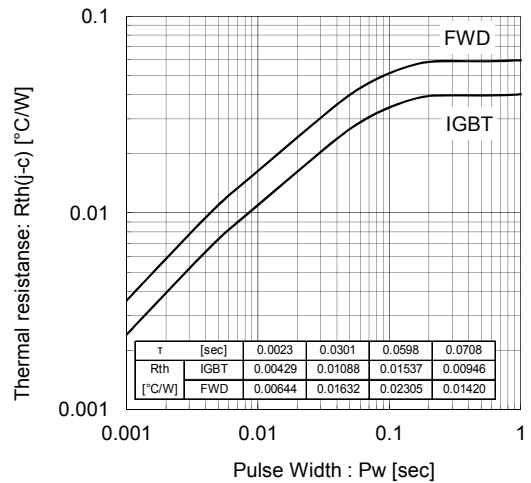


[INVERTER]

Reverse Recovery Characteristics (typ.)  
V<sub>CC</sub>=600V, V<sub>GE</sub>=±15V, R<sub>G</sub>=0.62Ω, T<sub>J</sub>=125°C, 150°C

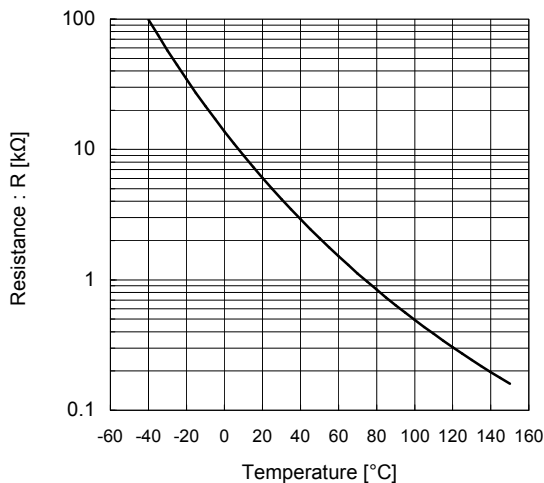


Transient Thermal Resistance (max.)

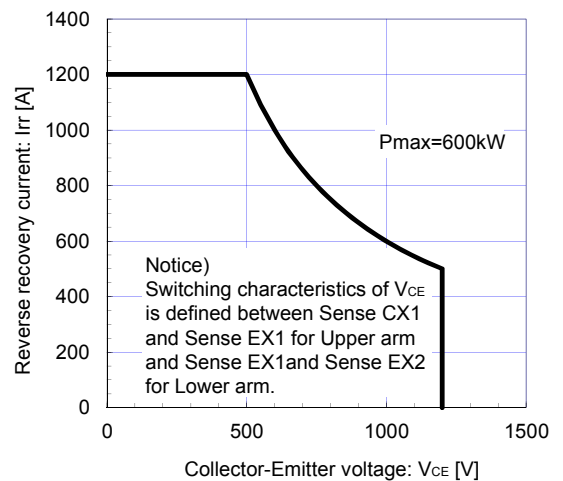


[THERMISTOR]

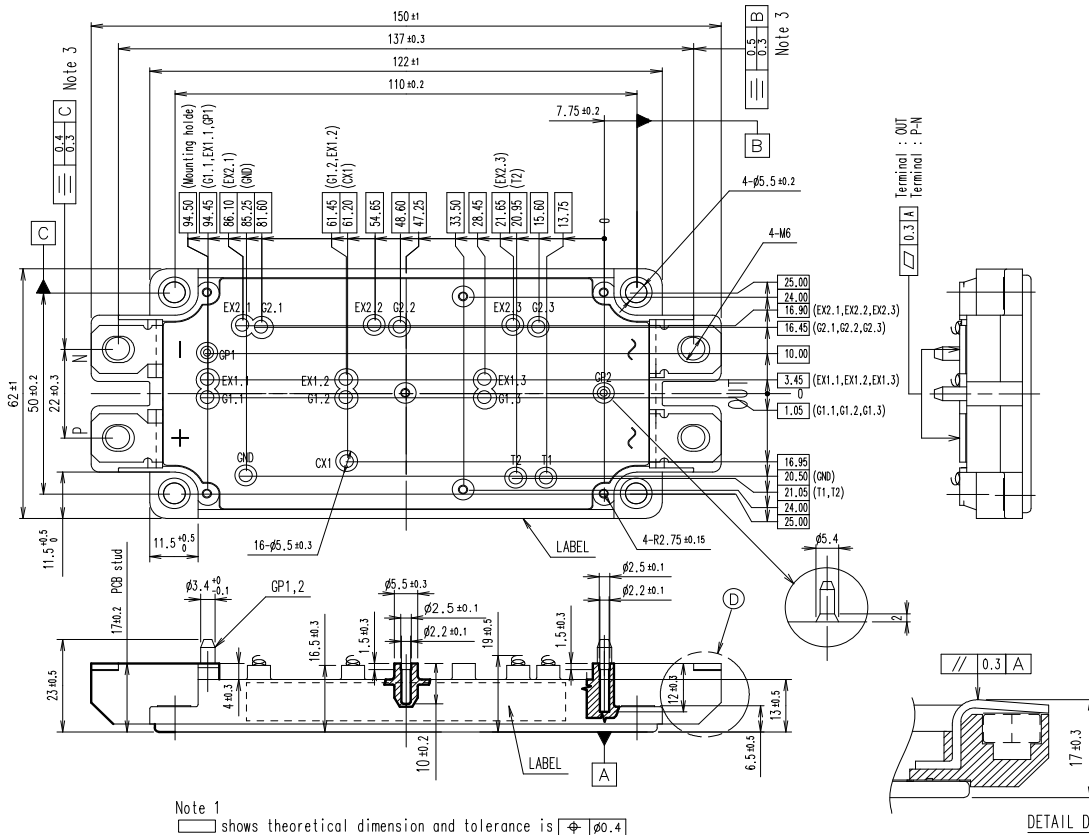
Temperature characteristic (typ.)



FWD safe operating area (max.)  
T<sub>J</sub>=150°C



Outline Drawings (Unit : mm)



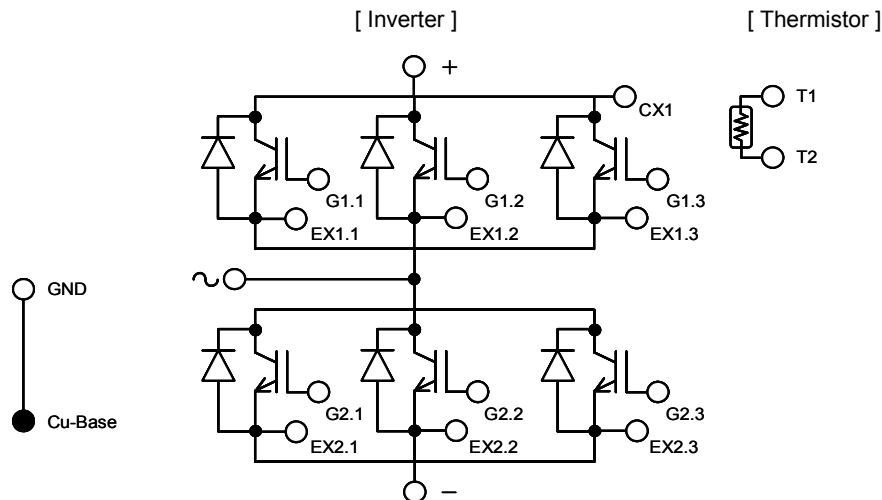
Note 1  
 shows theoretical dimension and tolerance is  $\pm 0.4$

Note 2  
 Rule for PCB  
 · Guide pin hole :  $\phi 4.0 \pm 0.1$   
 · Guide pin distance :  $94.45 \pm 0.1$   
 · Spring contact pad :  $\phi 3.8 \pm 0.2$   
 · Position tol. pad :  $\pm 0.4$

Weight: 300g (typ.)

Note 3  
  
 Upper value : Terminal hole center  
 Lower value : Nut hole  
 (Including margin of the nut position.)

Equivalent circuit



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**IGBT Modules**

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